

# ISO508

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## Uni-Directional ISOLATED DIGITAL COUPLERS

### FEATURES

- **LOW POWER CONSUMPTION:**  
< 12mW per Channel Typ.
- **1500Vrms ISOLATION:**  
100% Tested by Partial Discharge
- **ASYNCHRONOUS OR SYNCHRONOUS OPERATION**
- **DOUBLE BUFFERED DESIGN FOR EASY INTEGRATION INTO BUS-BASED SYSTEMS**
- **TRI-STATE OUTPUTS**
- **24-PIN PDIP OR GULL WING PACKAGES**
- **2MWORDS/SEC TRANSFER RATE**
- **1μSEC TRANSIENT RECOVERY**

### APPLICATIONS

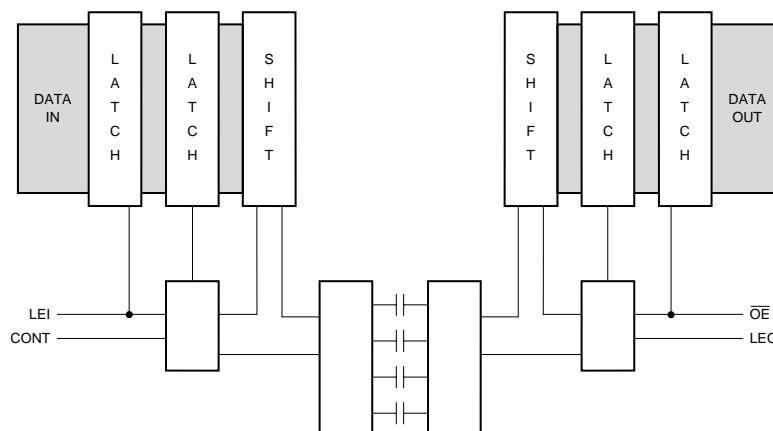
- **PARALLEL ADCs/DACs**
- **DIGITAL INTERFACES**
- **DIGITAL TRANSMISSION**
- **GROUND-LOOP ISOLATION**

### DESCRIPTION

ISO508 is an 8-channel, isolated, digital coupler based on the Burr-Brown capacitive barrier technology. The ISO508 has additional circuitry to ensure DC accuracy and overcome the edge-sensitive nature of normal capacitive devices even on power-up conditions. The novel circuitry involved will restore the correct output after a transient interruption should that be necessary.

The ISO508 is designed with input and output buffers for ease of integration into a  $\mu$ P bus system. The output buffer has tri-state capability, and by the use of OE, the output data bus lines can be made to go high impedance. This feature of the ISO508, which allows multiple access to a data bus, requires extra circuitry when using an alternative solution.

ISO508 will transfer an 8-bit word at rates up to 2Mwords/s without the skew problems associated in implementing this function with optocouplers. The ISO508 is available in 24-pin PDIP or 24-pin Gull Wing packages. Both are specified for operation from  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ .



# SPECIFICATIONS

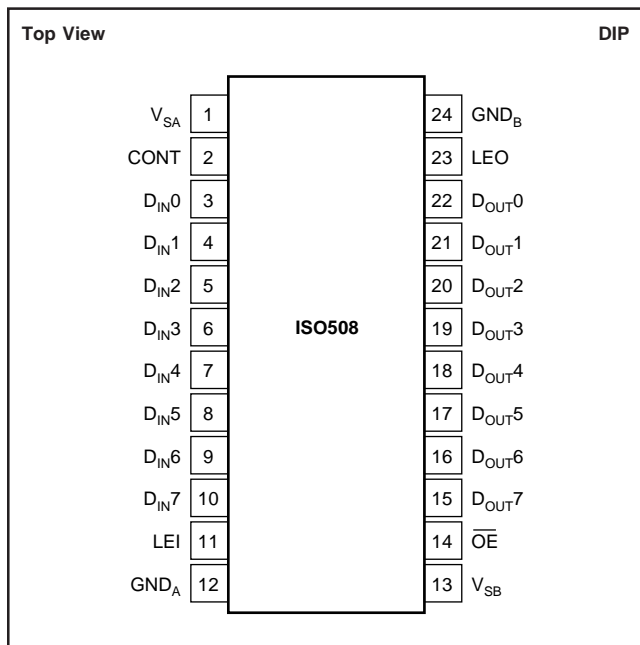
At  $T_A = +25^\circ\text{C}$ , and  $V_S = +5\text{V}$ , unless otherwise noted.

PARAMETER	CONDITIONS	ISO508P, P-U			UNITS
		MIN	TYP	MAX	
<b>ISOLATION</b>					
Rated Voltage, Continuous	$V_{ISO}$ 50Hz, 60Hz	1500			V
Partial Discharge Voltage	1s, 5x5pC/cycle <sup>(1)</sup>	2500			V
Barrier Impedance			>10 <sup>14</sup> , 10		$\Omega\text{pF}$
Leakage Current	240V, 60Hz 2500V, 50Hz		1	12	$\mu\text{A}$
Creepage Distance	PDIP = "P" Package		11		mm
Internal Isolation Distance	PDIP = "P" Package		0.1		mm
Transient Recovery Time	5kV/ $\mu\text{s}$ Edge			1	$\mu\text{s}$
<b>DC CHARACTERISTICS</b>					
High Level Input Voltage	$V_{IH}$ See Note 2	2			V
Low Level Input Voltage	$V_{IL}$ See Note 2			0.8	V
Input Pull-Down Current (Cont, $\overline{OE}$ )	$I_{PD}$ $V_{IN} = 5\text{V}$	5		50	$\mu\text{A}$
Input Leakage Current	$I_L$ LEI, LEO, D0-7		1		nA
High Z Leakage Current	$I_H$		1		nA
Input Capacitance	$C_{IN}$		5		pF
High Level Output Voltage	$V_{OH}$ $V_S = 4.4 - 4.5$ , $I_{OH} = 6\text{mA}$	$V_S - 1$			V
Low Level Output Voltage	$V_{OL}$ $I_{OL} = 6\text{mA}$			0.4	V
Output Short-Circuit Current	$I_{OS}$ 1 second, max		30		mA
<b>TIMING</b>					
LE Width (LOW)	$t_{WL}$	50			ns
LE Width (HIGH)	$t_{HL}$	15			ns
Data Set-Up to LEI	$t_{SU}$ LEI HI to LO	0			ns
Data Hold from LEI	$t_H$ LEI HI to LO	20			ns
Propagation Delay	$t_{PD}$ Data In to Data Out (Cont) LEI LOW to Data Out (Sync)			1000	ns
Data Output Delay	$t_{DD}$ LEO High to Data Out Change			520	ns
Output Rise and Fall Time	$t_{OD}$ 10% to 90%, $C_L = 50\text{pF}$		9	35	ns
Output Enable	$t_{OE}$ $\overline{OE}$ to Data Valid High or Low			14	ns
Output Disable	$t_{DIS}$ $\overline{OE}$ to Data Hi-Z			35	ns
Skew			5	25	ns
Max Data Transfer Rate (Sync)		2			Mw/s
(Cont)		1			Mw/s
<b>POWER</b>					
Supply Voltage	$V_{SA}$ , $V_{SB}$ Either Side	4.5		5.5	V
Supply Current	$I_{SA}$ Transmit Side DC		5	10	mA
	Transmit Side DC Max Rate		7	15	mA
Supply Current	$I_{SB}$ Receive Side DC		8	12	mA
	Receive Side Max Rate		12	20	mA
<b>TEMPERATURE RANGE</b>					
Operating		-40		+85	$^\circ\text{C}$
Storage		-40		+125	$^\circ\text{C}$
Thermal Resistance, $\theta_{JA}$			75		$^\circ\text{C/W}$

NOTES: (1) All devices receive a 1s test. Failure criterion is 5 pulses of  $\geq 5\text{pC}$  per cycle. (2) Logic inputs are HCT-type and thresholds are a function of power supply voltage with approximately 400mV hysteresis.

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## PIN CONFIGURATION



## FUNCTIONAL DESCRIPTION

NAME	FUNCTION
D <sub>IN</sub> (0 - 7)	Input Data Bus. Inputs are CMOS/TTL compatible.
D <sub>OUT</sub> (0 - 7)	Output Data Bus. Outputs are TTL compatible.
LEI	Input Latch Enable. Latch enable signal for the input data buffer. A logic LOW will latch the input data preventing further changes being made before data transmission across the barrier, and transmit if in synchronous mode. A logic HIGH will allow the data to pass from the input pins to the input buffer.
LEO	Output Latch Enable. Latch enable signal for the output data buffer. A logic LOW will latch the internal data to the output pins and prevent further changes to the output data. A logic HIGH will allow the internal data to be passed to the output pins as soon as it becomes available.
CONT	Synchronous/Asynchronous Mode Select. A logic HIGH selects asynchronous mode. A logic LOW selects synchronous mode.
$\overline{OE}$	Output Tri-State Enable. Makes the output data pins high impedance to allow multiple parallel access to the data bus. A logic HIGH will make D <sub>OUT</sub> (0 - 7) high impedance. A logic LOW will allow D <sub>OUT</sub> (0 - 7) to be driven to the correct logic level.

## ABSOLUTE MAXIMUM RATINGS

Supply Voltage: V <sub>SA</sub> .....	-0.5V to +6V
V <sub>SB</sub> .....	-0.5V to +6V
Maximum Input Current, any Input Pin .....	20mA
Continuous Isolation Voltage .....	1500Vrms
Storage Temperature .....	-40°C to +125°C
Lead Temperature (soldering, 10s) .....	+260°C

## PACKAGE INFORMATION

PRODUCT	PACKAGE	PACKAGE DRAWING NUMBER <sup>(1)</sup>
ISO508P	24-Pin Plastic DIP	167
ISO508P-U	24-Pin Gull Wing Surface Mount	167-4

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book.



## ELECTROSTATIC DISCHARGE SENSITIVITY

Electrostatic discharge can cause damage ranging from performance degradation to complete device failure. Burr-Brown Corporation recommends that all integrated circuits be handled and stored using appropriate ESD protection methods.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet published specifications.

# OPERATION

ISO508 has two modes of operation: synchronous and asynchronous. The mode is selected by the CONT pin. CONT held low selects synchronous operation while CONT held high will select asynchronous operation. In synchronous mode the user has control of the time at which the data is transmitted across the barrier, while in asynchronous mode the data is continually transmitted across the barrier under the internal logic control. The input latches and output latches are level sensitive.

## SYNCHRONOUS MODE

With CONT held low, the input data is transmitted across the barrier under the control of LEI. When LEI is held low, no data is passed to the input buffer and no barrier transmission takes place. When LEI goes high, data is transferred to the input buffer. On the falling edge of LEI the data is then transmitted across the barrier.

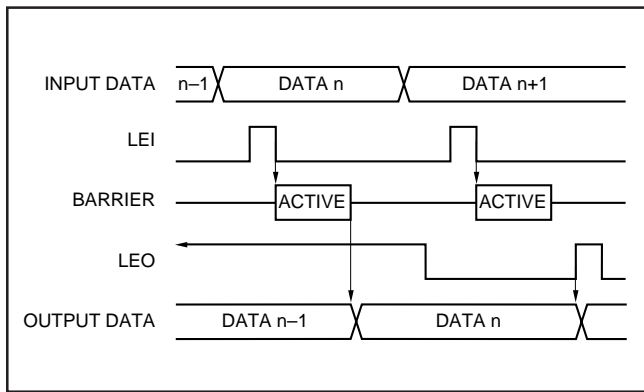


FIGURE 1. Data Transfer—Synchronous Mode.

If LEI is taken high when transmission is in progress, the input data is recaptured in the input buffer without interfering with the transmitting data. If LEI then goes low while transmission is still in progress the current transmission will be terminated and restarted with the new data. The last full data transmission will not be affected.

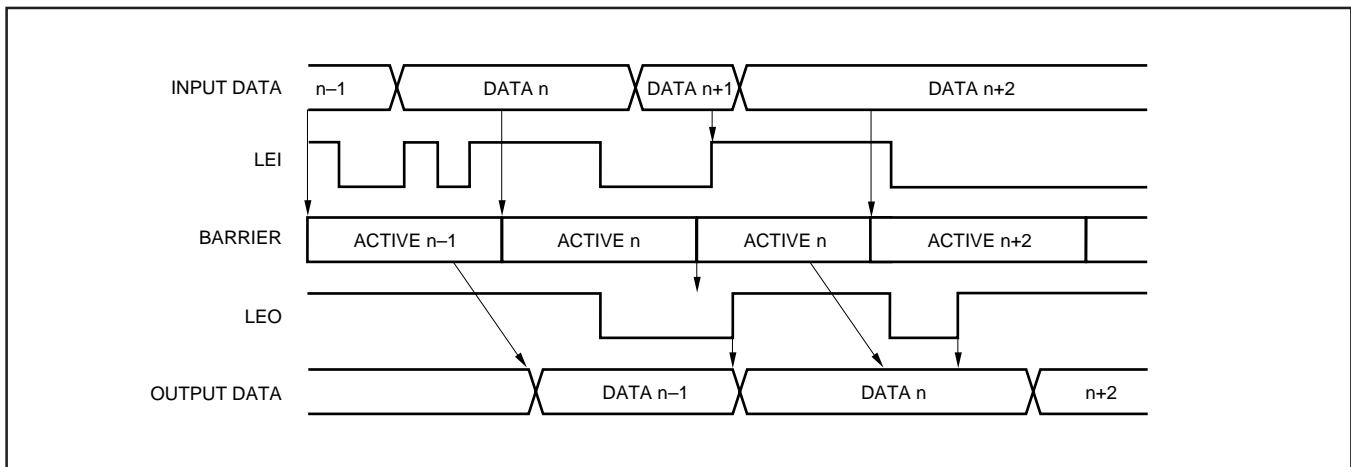


FIGURE 3. Data Transfer—Asynchronous Mode.

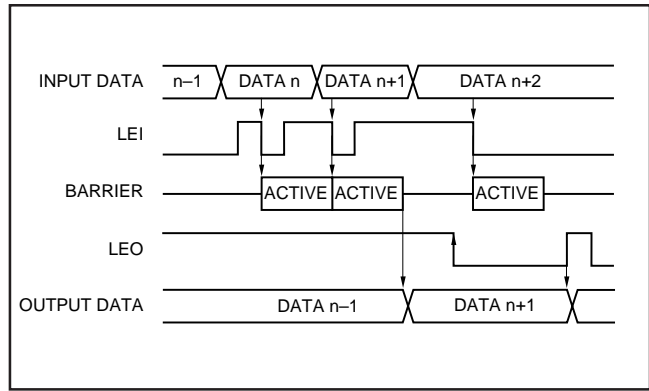


FIGURE 2. Data Transfer—Synchronous Mode Restart.

The output data changes under the control of LEO. If LEO is high at the end of a transmission, the output data will change immediately the transmission is complete. If LEO is low at the end of transmission, the output data will change when LEO goes high. In both cases all data bits will change together guaranteeing the specified skew performance. Transmitted data can be ignored selectively, if desired, by maintaining LEO low until the desired data is available.

## ASYNCHRONOUS MODE

When CONT is held high, the internal transmission circuit is in control and will initiate data transmission asynchronously at 1MWords/s i.e., 1Mbps on each of the 8 channels.

The asynchronous mode runs continuously under the internal controls. LEI can serve as an input data latch, but will not control the data transmission across the barrier. As in the synchronous mode, LEI and LEO can be used to select or ignore input or output data respectively.

## DATA CORRUPTION

In either synchronous or asynchronous mode if the data is upset by a transient the complete transmission is invalid. However, in asynchronous mode the data is being sent continuously and will therefore correct the corrupted information within a maximum of 1µs. In synchronous mode, data transfer is under the control of the user, and retransmission would be required by the software.

## DATA TRANSMISSION AND JITTER

Because the internal 20MHz clock is free-running, two “jitter” conditions are possible. In synchronous mode when

LEI goes low data will be transmitted (clocked) across the barrier. Depending on when LEI goes low, in relation to the internal clock cycle, will determine the “jitter” between successive input data transfers. This can be maximum of 50ns.

In asynchronous mode the input data is transferred by the internal clock and logic control, i.e., 2 sync. Clock cycles., ( $S_0$ , and  $S_1$ ), 8 data clock cycles. Depending on when the input data is presented, in relation to the start of the data block transmission, will determine the “jitter” between successive input data transfers. This can be maximum of 500ns.

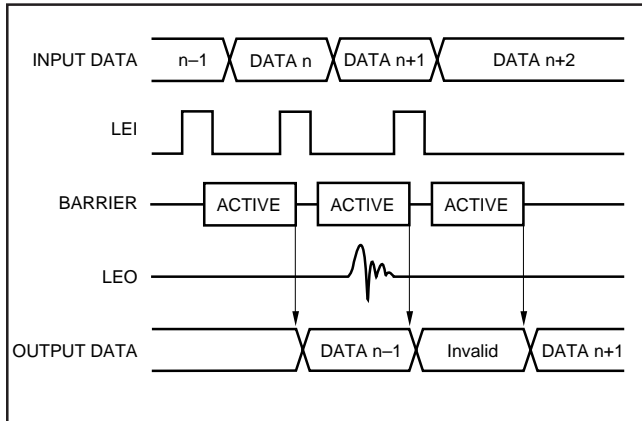


FIGURE 4. Data Corruption.

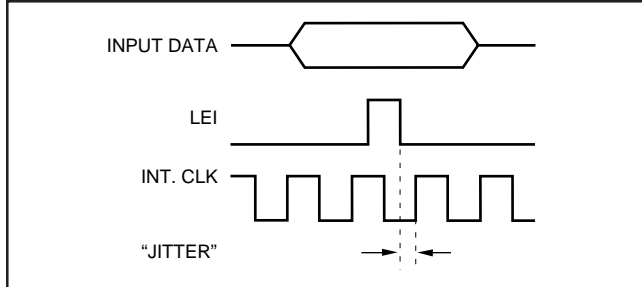


FIGURE 5. Jitter in Synchronous Mode.

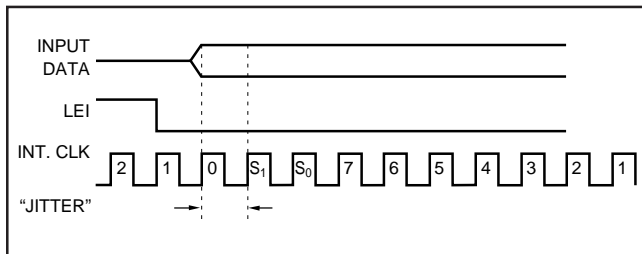


FIGURE 6. Jitter in Asynchronous Mode.

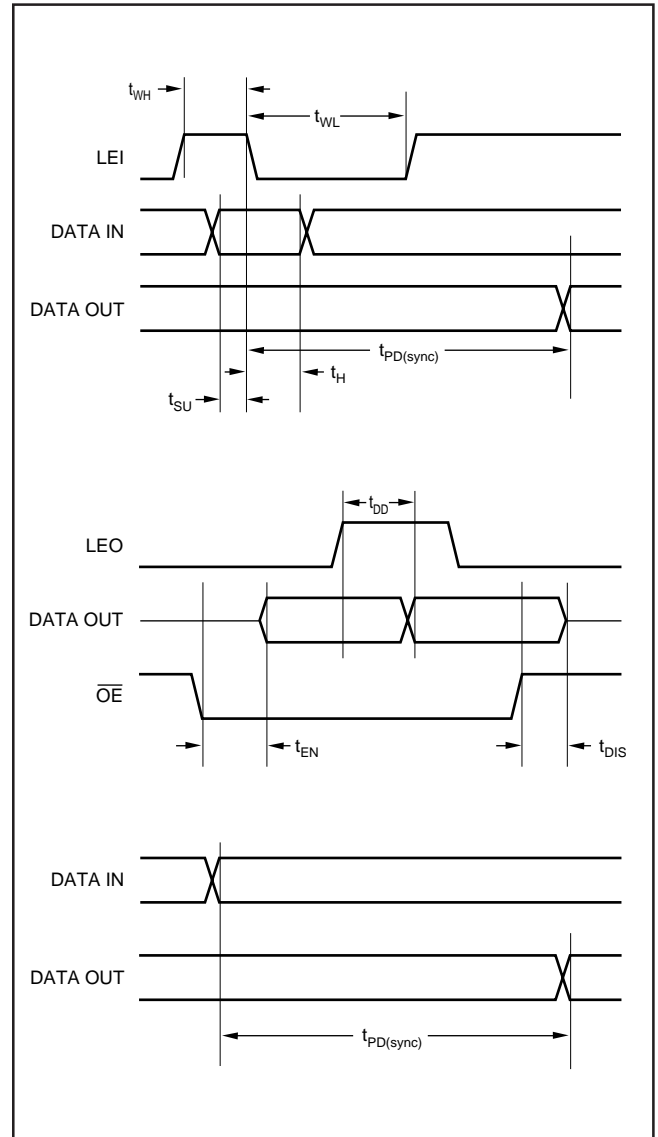


FIGURE 7. Timing Diagrams.

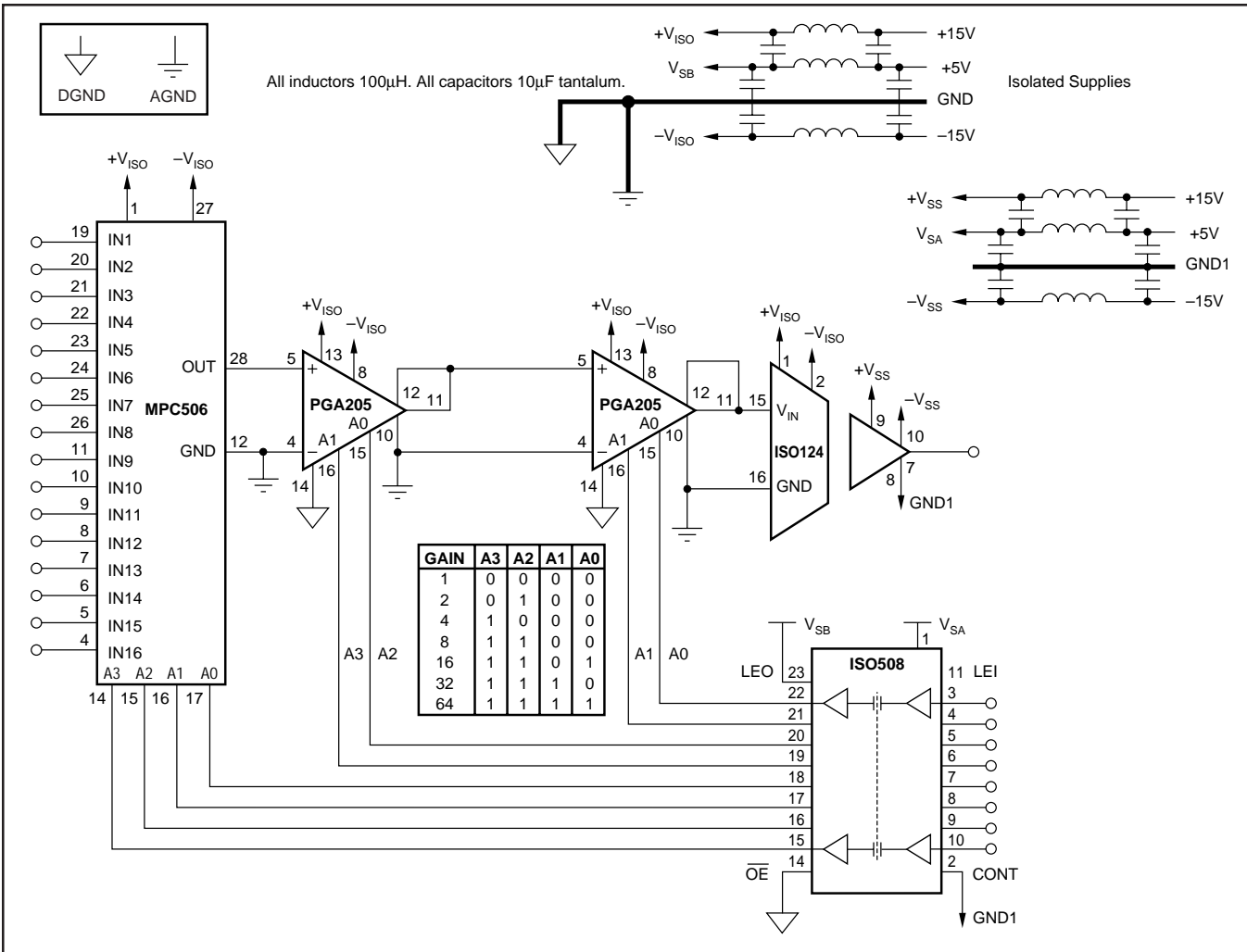


FIGURE 8. Isolated 16-Channel Variable Gain DAS.

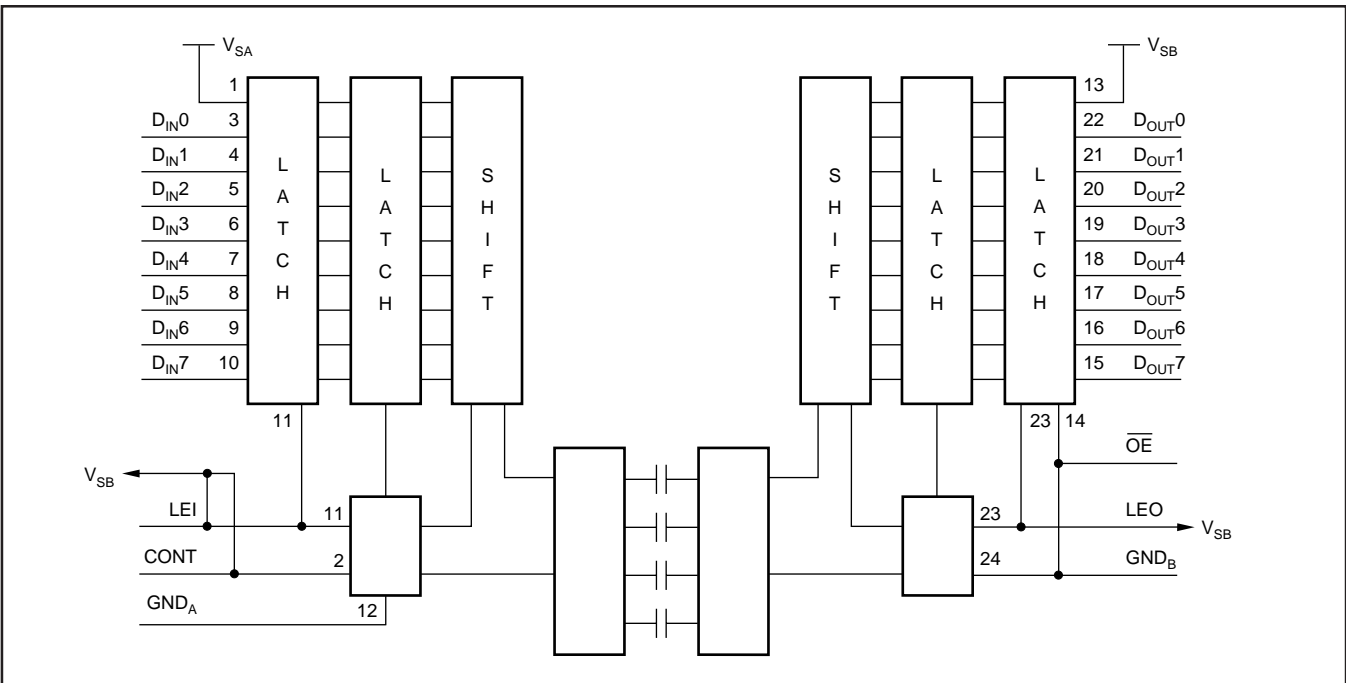


FIGURE 9. Isolated 8-Channel Output Bus (Asynchronous Operation).